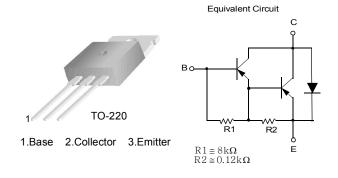


October 2008

TIP125/TIP126/TIP127 PNP Epitaxial Darlington Transistor

- Medium Power Linear Switching Applications
- Complementary to TIP120/121/122



Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage : TIP125	- 60	V
	: TIP126	- 80	V
	: TIP127	- 100	V
	Collector-Emitter Voltage : TIP125	- 60	V
V_{CEO}	: TIP126	- 80	V
	: TIP127	- 100	V
V _{EBO}	Emitter-Base Voltage	- 5	V
I _C	Collector Current (DC)	- 5	Α
I _{CP}	Collector Current (Pulse)	- 8	Α
I _B	Base Current (DC)	- 120	mA
P _C	Collector Dissipation (T _a =25°C)	2	W
	Collector Dissipation (T _C =25°C)	65	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

 $^{^{\}star}$ These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

$\textbf{Electrical Characteristics*} \ \textbf{T}_{a} = 25^{\circ}\textbf{C} \ \textbf{unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage : TIP125 : TIP126 : TIP127	I _C = -100mA, I _B = 0	-60 -80 -120			V V V
I _{CEO}	Collector Cut-off Current : TIP125 : TIP126 : TIP127	$V_{CE} = -30V, I_{B} = 0$ $V_{CE} = -40V, I_{B} = 0$ $V_{CE} = -50V, I_{B} = 0$			-2 -2 -2	mA mA mA
I _{CBO}	Collector Cut-off Current : TIP125 : TIP126 : TIP127	$V_{CB} = -60V, I_{E} = 0$ $V_{CB} = -80V, I_{E} = 0$ $V_{CB} = -100V, I_{E} = 0$			-1 -1 -1	mA mA mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = -5V, I_{C} = 0$			-2	mA
h _{FE}	* DC Current Gain	$V_{CE} = -3V, I_{C} = 0.5A$ $V_{CE} = -3V, I_{C} = -3A$	1000 1000			
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_C = -3A$, $I_B = -12mA$ $I_C = -5A$, $I_B = -20mA$			-2 -4	V V
V _{BE} (on)	* Base-Emitter On Voltage	$V_{CE} = -3V, I_{C} = -3A$			-2.5	V
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E = 0, f = 0.1MHz			300	pF

^{*} Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

Typical Characteristics

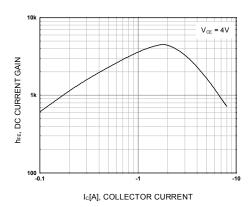


Figure 1. DC current Gain

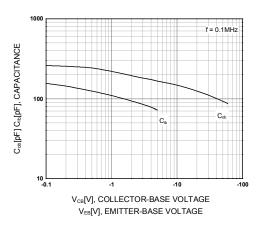


Figure 3. Output and Input Capacitance vs. Reverse Voltage

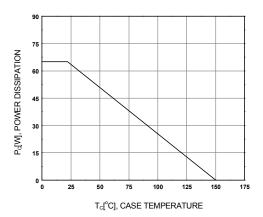


Figure 5. Power Derating

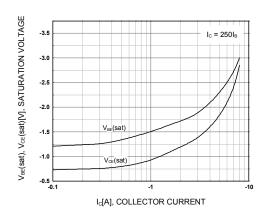


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

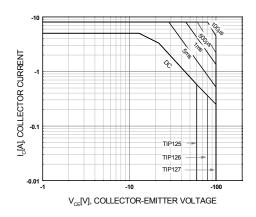
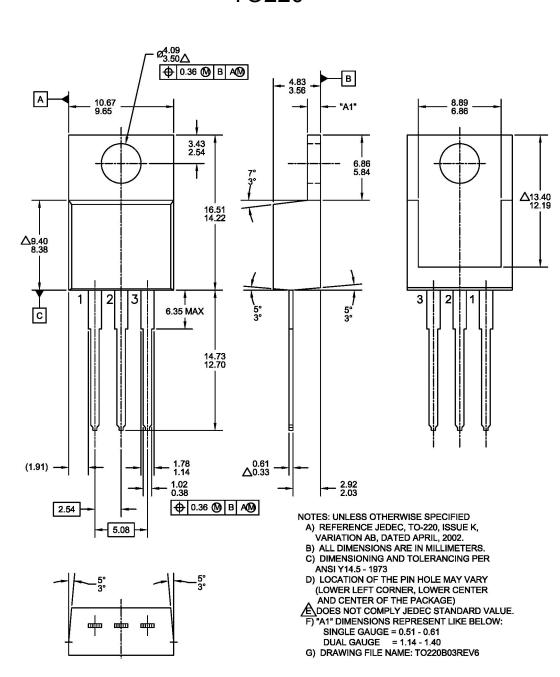


Figure 4. Safe Operating Area

Mechanical Dimensions

TO220







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